Diode Modules MDx1200

$I_{F(AV)}$	**1200A**
V_{RRM}	**600~1800V**
I_{FSM}	**34 A×10^3**
I^2t	**5780A^2 S*10^3**

Features：

- Isolated mounting base 2500V~
- Pressure contact technology with Incrtased power cycling capability
- Space and weight savings

Typical Applications

- AC/DC Motor drives
- Various rectifiers
- DC supply for PWM inverter

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T_j(°C)	VALUE			UNIT
				Min	Type	Max	
$I_{F(AV)}$	Mean forward current	180° half sine wave 50Hz Single side cooled,T_C=100°C	150			1200	A
$I_{F\ (RMS)}$	RMS forward current		150			1884	A
V_{RRM}	Repetitive peak reverse voltage	V_{RRM} tp=10ms V_{RsM}= V_{RRM}+100V	150	600		1800	V
I_{RRM}	Repetitive peak current	at V_{RRM}	150			50	mA
I_{FSM}	Surge forward current	10ms half sine wave V_R=0.6V_{RRM}	150			34	KA
I^2t	I^2T for fusing coordination					5780	A^2s*10^3
V_{FO}	Threshold voltage		150			0.71	V
r_F	Forward slop resistance					0.11	mΩ
V_{FM}	Peak forward voltage	I_{FM}=3000A	25			1.86	V
$R_{th(j-c)}$	Thermal resistance Junction to case	At 180^0 sine, Single side cooled				0.040	°C /W
$R_{th(c-h)}$	Thermal resistance case to heat sink	At 180^0 sine, Single side cooled				0.020	°C /W
V_{iso}	Isolation voltage	50Hz,R.M.S,t=1min, I_{iso}:1mA(max)		2500			V
F_m	Terminal connection torque(M12)				14		N·m
	Mounting torque(M8)				12		N·m
T_{stg}	Stored temperature			-40		125	°C
W_t	Weight				3800		g
Outline							

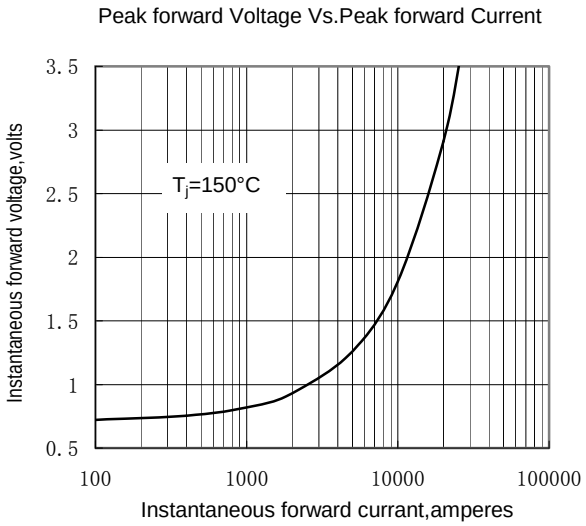

Fig.1

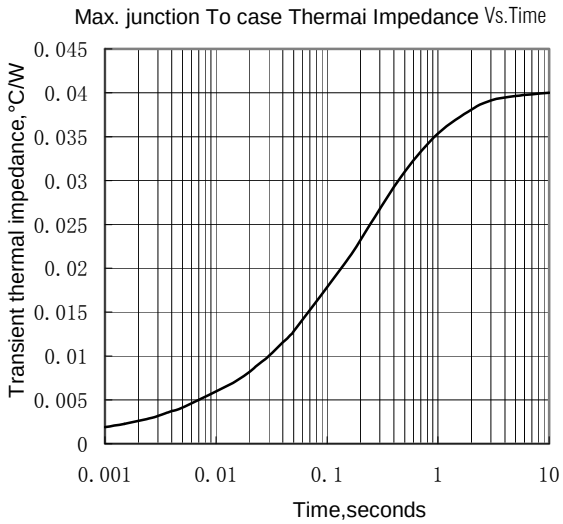

Fig.2

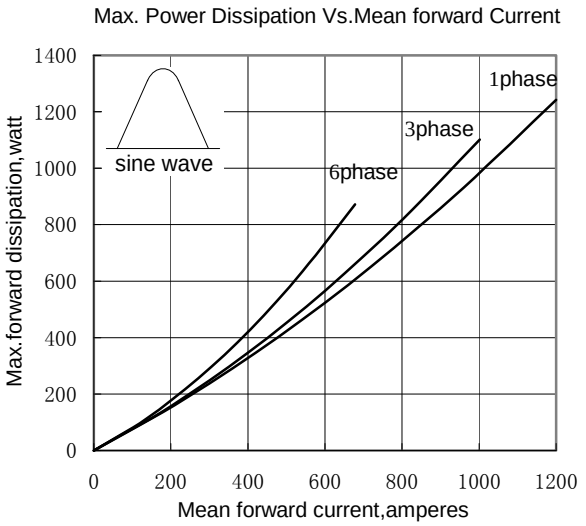

Fig.3

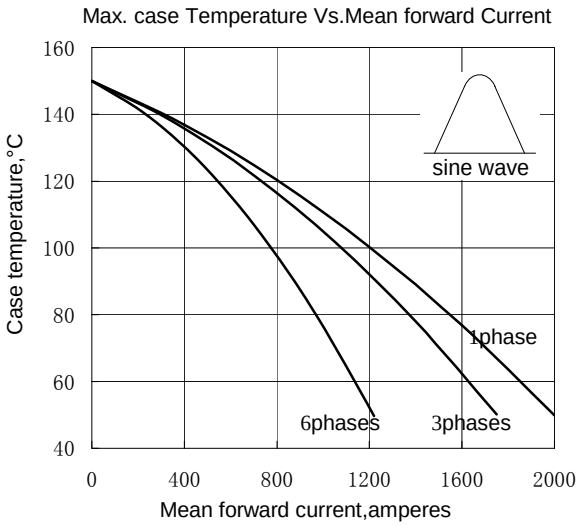

Fig.4

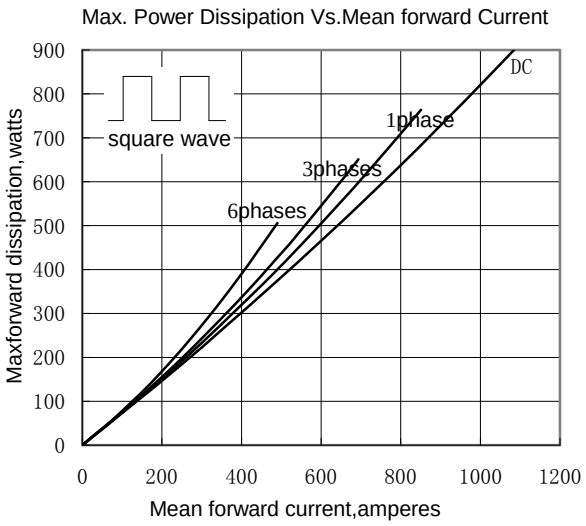

Fig.5

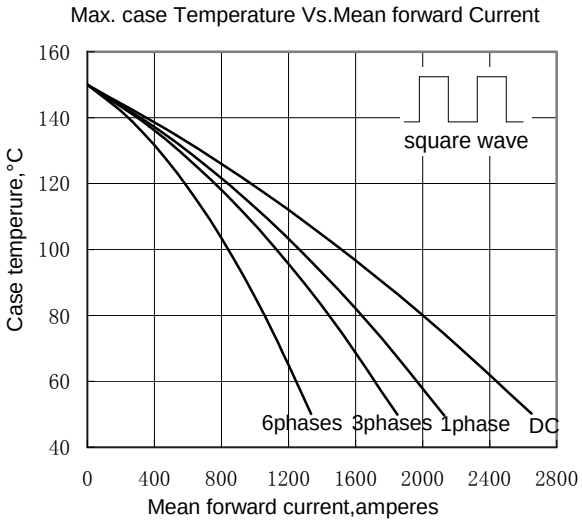

Fig.6

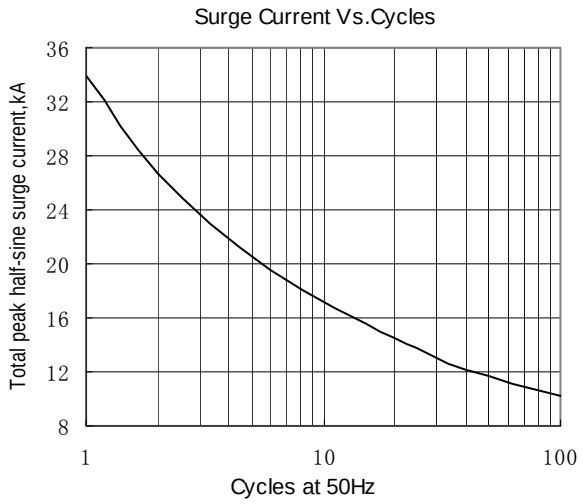

Fig.7

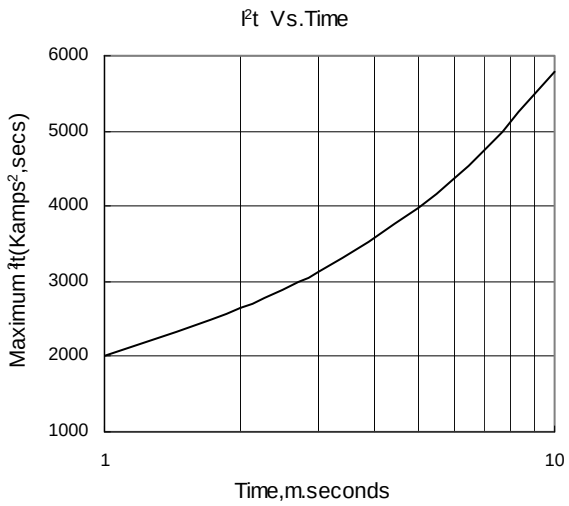

Fig.8

Outline: